

International **IR** Rectifier

PD-2.328 rev. A 12/97

SD41

SCHOTTKY RECTIFIER

30 Amp

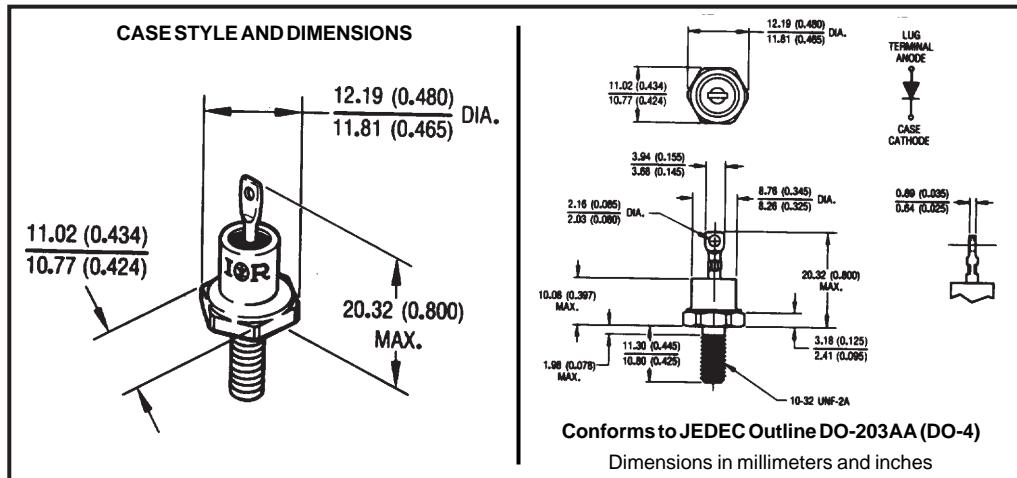
Major Ratings and Characteristics

Characteristics	SD41	Units
$I_{F(AV)}$ Rectangular waveform	30	A
V_{RWM}	35/45	V
I_{FSM} @ 60Hz	600	A
V_F @ 60Apk, $T_J = 150^\circ C$	0.70	V
T_J	-65 to 150	°C

Description/Features

The SD41 Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to $150^\circ C$ junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- $150^\circ C T_J$ operation
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Hermetic packaging



Voltage Ratings

Part number	SD41		
V_R Max. DC Reverse Voltage (V)			
V_{RWM} Max. Working Peak Reverse Voltage (V)		35/45	(1)

(1) For SD41 rated V_{RWM} and $V_{RRM} = 45V$ @ $T_J = 25^\circ C$, = 35V @ $T_J = 150^\circ C$ **Absolute Maximum Ratings**

Parameters	SD41	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	30	A	50% duty cycle @ $T_C = 96^\circ C$, rectangular waveform
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	600	A	60Hz half cycles sine wave or 5ms rectangular pulse Following any rated load condition and with rated V_{RRM} applied

Electrical Specifications

Parameters	SD41	Units	Conditions
V_{FM} Max. Forward Voltage Drop (2) * See Fig. 1	0.58	V	@ 30A
	0.75	V	@ 60A
	0.70	V	@ 60A
I_{RM} Max. Reverse Leakage Current (2) * See Fig. 2	50	mA	$T_J = 25^\circ C$
	125	mA	$T_J = 125^\circ C$
C_T Max. Junction Capacitance	2000	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) $25^\circ C$
L_S Typical Series Inductance	6.5	nH	Measured from top of terminal to mounting plane
dv/dt Max. Voltage Rate of Change (Rated V_R)	1000	V/ μs	

(2) Pulse Width < 300 μs , Duty Cycle < 2%**Thermal-Mechanical Specifications**

Parameters	SD41	Units	Conditions
T_J Max. Junction Temperature Range	-65 to 150	°C	
T_{stg} Max. Storage Temperature Range	-65 to 150	°C	
R_{thJC} Max. Thermal Resistance Junction to Case	2.0	°C/W	DC operation * See Fig. 4
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.50	°C/W	Mounting surface, smooth and greased
wt Approximate Weight	5.8(0.20)	g(oz.)	
T Mounting Torque	Min.	14(12)	Kg-cm (lbf-in)
	Max.	23(20)	Non-lubricated threads
Case Style	DO-203AA(DO-4)		JEDEC

* For Additional Information and Graphs, Please See the 21FQ Series

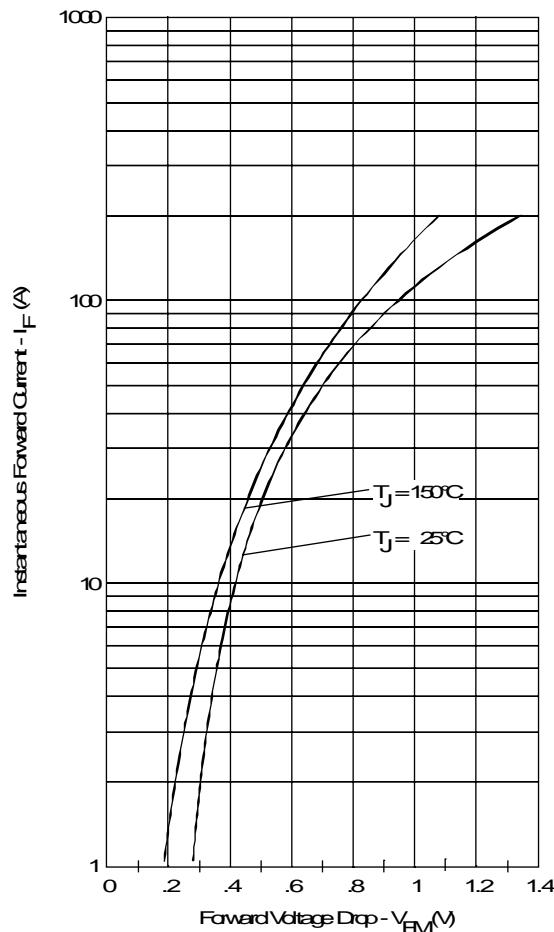


Fig. 1-Maximum Forward Voltage Drop Characteristics

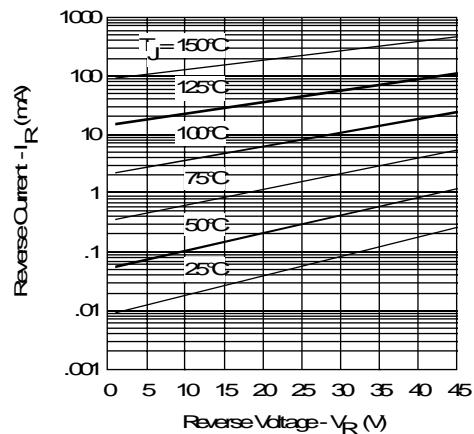


Fig. 2-Typical Values of Reverse Current Vs. Reverse Voltage

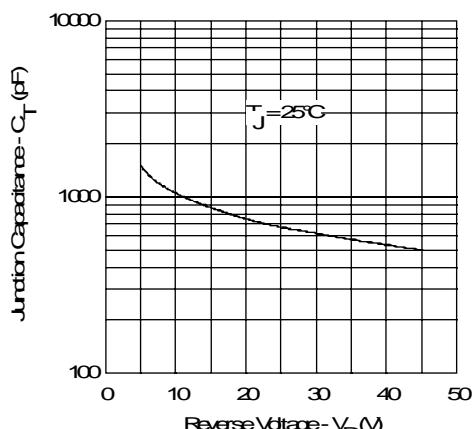


Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

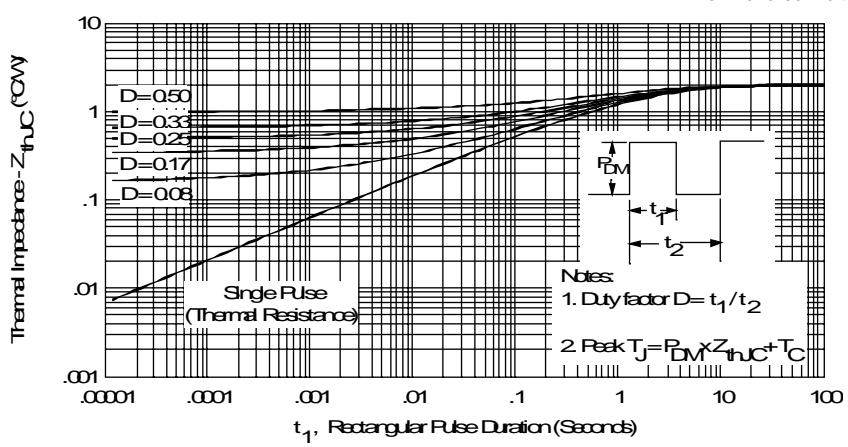


Fig. 4-Maximum Thermal Impedance Z_{thJC} Characteristics

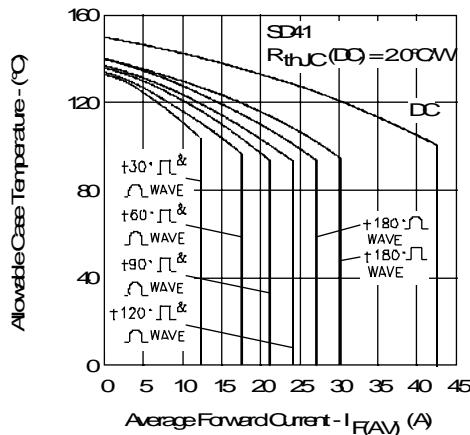


Fig.5-Maximum Allowable Case Temperature
Vs. Average Forward Current

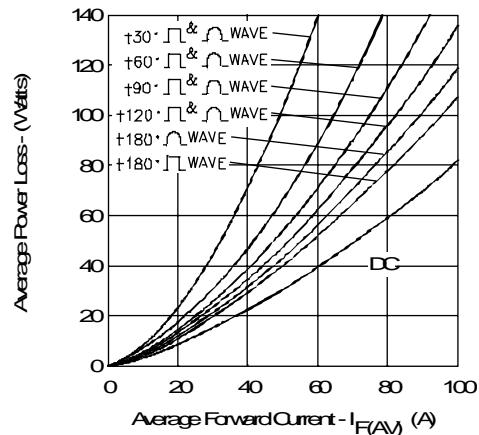


Fig.6-Forward Power Loss Characteristics

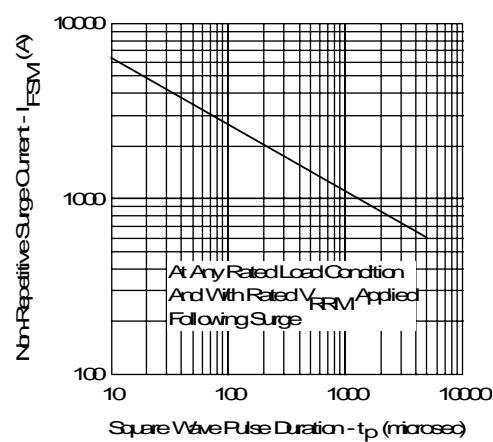


Fig.7-Max. Non-Repetitive Surge Current